

MP03XXX360

Dual Thyristor, Thyristor/Diode Module

Replaces June 2001 version, DS4484-6.1

DS4484-7.0 July 2002

FEATURES

- Dual Device Module
- Electrically Isolated Package
- www.DataSmePressure Contact Construction
 - International Standard Footprint
 - Alumina (Non Toxic) Isolation Medium

APPLICATIONS

- Motor Control
- Controlled Rectifier Bridges
- Heater Control
- AC Phase Control

KEY PARAMETERS

| $\mathbf{V}_{\mathtt{DRM}}$ | 1200V |
|-----------------------------|--------|
| I _{T(AV)} | 352A |
| TSM(per arm) | 10600A |
| V_{isol} | 3000V |

| Code | Circuit |
|------|------------------------------------|
| НВТ | · → · → · |
| HBP | → → ₁ |
| HBN | → ·• |

Fig.1 Circuit diagrams

VOLTAGE RATINGS

| Type Number | Repetitive Peak Voltages V _{DRM} V _{RRM} V | Conditions |
|---------------|--|--|
| MP03XXX360-12 | 1200 | $T_{vj} = 0^{\circ} \text{ to } 130^{\circ}\text{C},$ |
| MP03XXX360-10 | 1000 | $I_{DRM} = I_{RRM} = 50 \text{mA}$ $V_{DSM} = V_{RSM} =$ |
| MP03XXX360-08 | 800 | $V_{DRM} = V_{RRM} + 100V$ respectively |

Lower voltage grades available.

Outline type code: MP03

Fig. 2 Electrical connections - (not to scale)

ORDERING INFORMATION

Order As:

MP03HBT360-12 or MP03HBT360-10 or MP03HBT360-08 MP03HBN360-12 or MP03HBN360-10 or MP03HBN360-08 MP03HBP360-12 or MP03HBP360-10 or MP03HBP360-08

Note: When ordering, please use the complete part number.



ABSOLUTE MAXIMUM RATINGS - PER ARM

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

| Symbol | Parameter Test Conditions | | Max. | Units | |
|--------------------|-----------------------------------|---|--------------------------|-----------------------|-----|
| I _{T(AV)} | Mean on-state current | Half wave resistive load | T _{case} = 75°C | 352 | Α |
| ataSheet4U.cor | n | | T _{case} = 85°C | 306 | Α |
| I _{T(RMS} | RMS value | T _{case} = 75°C | | 553 | Α |
| I _{TSM} | Surge (non-repetitive) on-current | 10ms half sine, T _j = 130°C | | 10.6 | kA |
| l²t | I ² t for fusing | $V_R = 0$ | | 560 x 10 ³ | A²s |
| I _{TSM} | Surge (non-repetitive) on-current | 10ms half sine, T _j = 130°C | | 8.5 | kA |
| l²t | I ² t for fusing | $V_R = 50\% V_{DRM}$ | | 360 x 10 ³ | A²s |
| V _{isol} | Isolation voltage | Commoned terminals to base plate. AC RMS, 1 min, 50Hz | | 3000 | V |

THERMAL AND MECHANICAL RATINGS

| Symbol | Parameter | Test Conditions | Min. | Max. | Units |
|-----------------------|---------------------------------------|-----------------------------|------|-------|-------------|
| R _{th(j-c)} | Thermal resistance - junction to case | dc | - | 0.105 | °C/kW |
| | (per thyristor or diode) | Half wave | - | 0.115 | °C/kW |
| | | 3 Phase | - | 0.12 | °C/kW |
| R _{th(c-hs)} | Thermal resistance - case to heatsink | Mounting torque = 5Nm | - | 0.05 | °C/kW |
| | (per thyristor or diode) | with mounting compound | | | |
| T _{vj} | Virtual junction temperature | Reverse (blocking) | - | 135 | °C |
| T _{stg} | Storage temperature range | - | -40 | 135 | °C |
| - | Screw torque | Mounting - M5 | - | 5(44) | Nm (lb.ins) |
| | | Electrical connections - M8 | - | 9(80) | Nm (lb.ins) |
| - | Weight (nominal) | - | - | 950 | g |



DYNAMIC CHARACTERISTICS - THYRISTOR

| | Symbol | Parameter | Test Conditions | Min. | Max. | Units |
|----|------------------------------------|--|--|------|------|-------|
| | I _{RRM} /I _{DRM} | Peak reverse and off-state current | At V_{RRM}/V_{DRM} , $T_j = 130^{\circ}C$ | - | 50 | mA |
| Ī | dV/dt | Linear rate of rise of off-state voltage | To 67% V _{DRM} , T _j = 130°C | - | 1000 | V/µs |
| | dl/dt | Rate of rise of on-state current | From 67% V_{DRM} to 600A, gate source 10V, 5Ω | - | 500 | A/μs |
| Sh | eet4U.com | | t _r = 0.5μs, T _j = 130°C | | | |
| | $V_{T(TO)}$ | Threshold voltage | At T _{vj} = 135°C. See note 1 | - | 0.75 | V |
| | r _T | On-state slope resistance | At T _{vj} = 135°C. See note 1 | - | 0.7 | mΩ |

Note 1: The data given in this datasheet with regard to forward voltage drop is for calculation of the power dissipation in the semiconductor elements only. Forward voltage drops measured at the power terminals of the module will be in excess of these figures due to the impedance of the busbar from the terminal to the semiconductor.

GATE TRIGGER CHARACTERISTICS AND RATINGS

| Symbol | Parameter | Test Conditions | Max. | Units |
|--------------------|---------------------------|---|------|-------|
| V _{GT} | Gate trigger voltage | $V_{DRM} = 5V$, $T_{case} = 25^{\circ}C$ | 3 | V |
| I _{GT} | Gate trigger current | $V_{DRM} = 5V$, $T_{case} = 25^{\circ}C$ | 150 | mA |
| $V_{\sf GD}$ | Gate non-trigger voltage | At V _{DRM} T _{case} = 125°C | 0.25 | V |
| V_{FGM} | Peak forward gate voltage | Anode positive with respect to cathode | 30 | V |
| V_{FGN} | Peak forward gate voltage | Anode negative with respect to cathode | 0.25 | V |
| V _{RGM} | Peak reverse gate voltage | - | 5 | V |
| I _{FGM} | Peak forward gate current | Anode positive with respect to cathode | 10 | А |
| P_{GM} | Peak gate power | See table fig. 5 | 100 | W |
| P _{G(AV)} | Mean gate power | - | 5 | W |



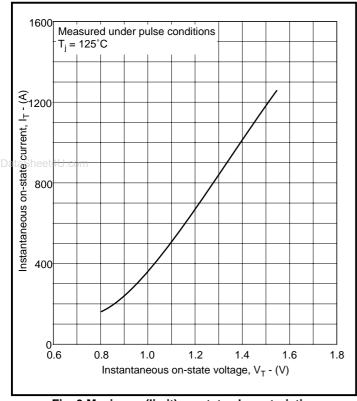
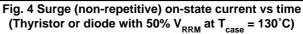
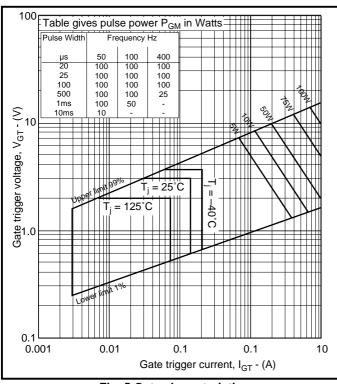


Fig. 3 Maximum (limit) on-state characteristics





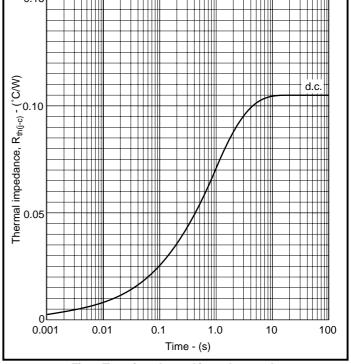


Fig. 5 Gate characteristics

Fig. 6 Transient thermal impedance - dc



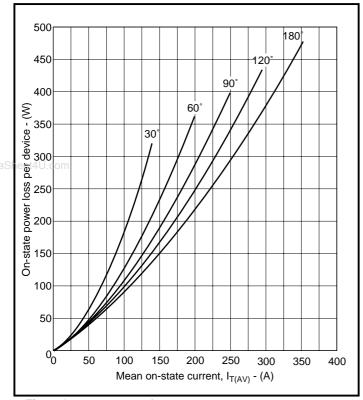


Fig. 7 On-state power loss per arm vs on-state current at specified conduction angles, sine wave 50/60Hz

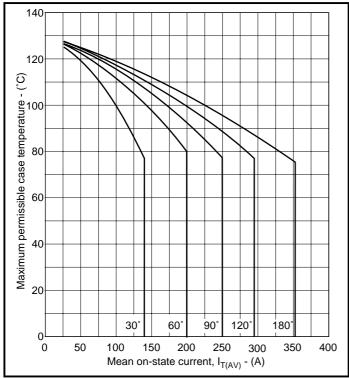


Fig. 9 Maximum permissible case temperature vs on-state current at specified conduction angles, sine wave 50/60Hz

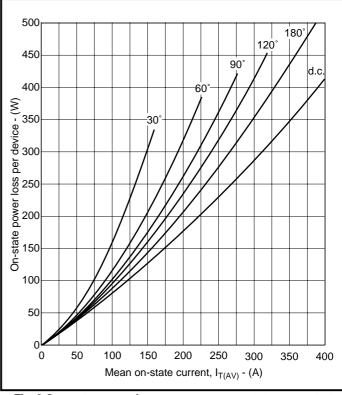


Fig. 8 On-state power loss per arm vs on-state current at specified conduction angles, square wave 50/60Hz

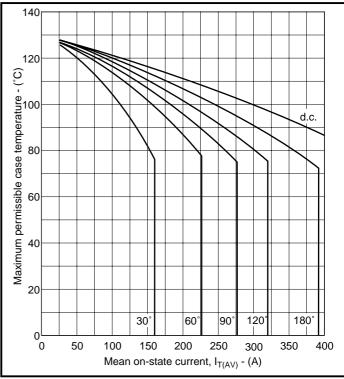


Fig. 10 Maximum permissible case temperature vs on-state current at specified conduction angles, square wave 50/60Hz



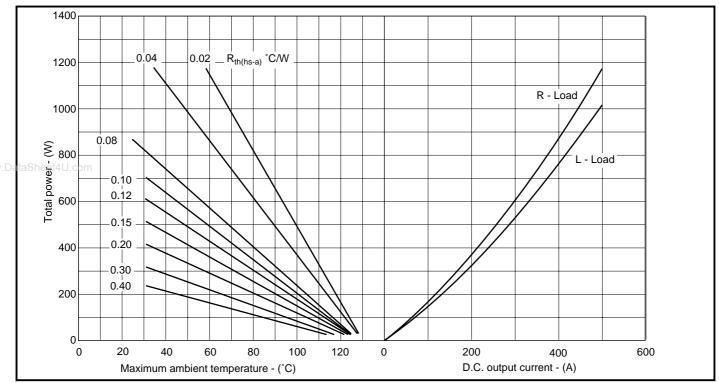


Fig. 11 50/60Hz single phase bridge dc output current vs power loss and maximum permissible ambient temperature for various values of heatsink thermal resistance

(Note: $R_{th(hs-a)}$ values given above are true heatsink thermal resistances to ambient and already account for $R_{th(c-hs)}$ module contact thermal)

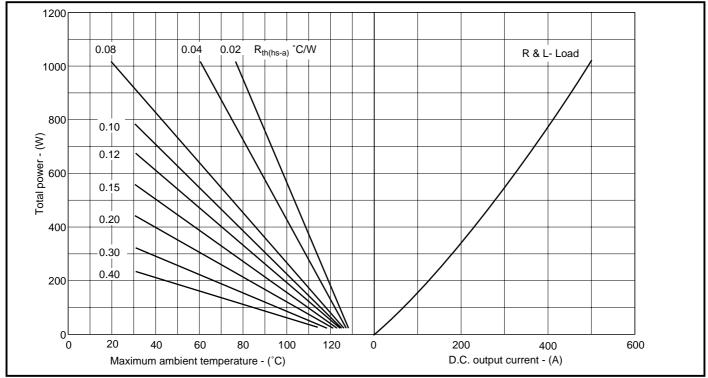


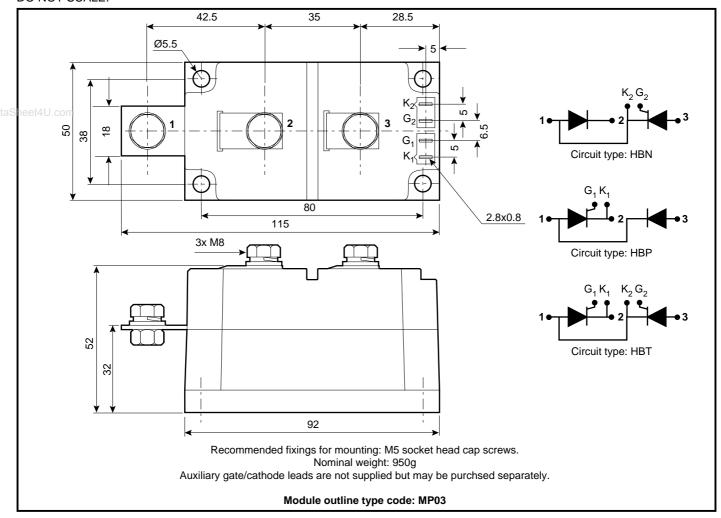
Fig. 12 50/60Hz 3- phase bridge dc output current vs power loss and maximum permissible ambient temperature for various values of heatsink thermal resistance

(Note: $R_{th(hs-a)}$ values given above are true heatsink thermal resistances to ambient and already account for $R_{th(c-hs)}$ module contact thermal)



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



MOUNTING RECOMMENDATIONS

Adequate heatsinking is required to maintain the base temperature at 75 °C if full rated current is to be achieved. Power dissipation may be calculated by use of $V_{T(TO)}$ and r_T information in accordance with standard formulae. We can provide assistance with calculations or choice of heatsink if required.

The heatsink surface must be smooth and flat; a surface finish of N6 (32 μ in) and a flatness within 0.05mm (0.002") are recommended.

Immediately prior to mounting, the heatsink surface should be lightly scrubbed with fine emery, Scotch Brite or a mild chemical etchant and then cleaned with a solvent to remove oxide build up and foreign material. Care should be taken to ensure no foreign particles remain.

An even coating of thermal compound (eg. Unial) should be applied to both the heatsink and module mounting surfaces. This should ideally be 0.05mm (0.002") per surface to ensure optimum thermal performance.

After application of thermal compound, place the module squarely over the mounting holes, (or 'T' slots) in the heatsink. Fit and finger tighten the recommended fixing bolts at each end. Using a torque wrench, continue to tighten the fixing bolts by rotating each bolt in turn no more than 1/4 of a revolution at a time, until the required torque of 6Nm (55lbs.ins) is reached on all bolts at both ends.

It is not acceptable to fully tighten one fixing bolt before starting to tighten the others. Such action may DAMAGE the module.



POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.



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Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

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No Annotation: The product parameters are fixed and the product is available to datasheet specification.

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